

Vishay Siliconix

0.4 Ω , Low Resistance and Capacitance, Dual DPDT / Quad SPDT Analog Switch

DESCRIPTION

The DG2523 and DG2524 are four-channel single-pole double-throw (SPDT) analog switches. The DG2523 has two control inputs that each controls a pair of single-pole double-throw (SPDT). It is also known as a two-channel double-pole double-throw (DPDT) configuration. The DG2524 has an $\overline{\text{EN}}$ pin to enable the device when the logic is low.

The parts are designed to operate from 1.8 V to 5.5 V single power rail. All switches conduct equally well in both directions, offering rail to rail signal witching and can be used both as multiplexers as well as de-multiplexers. The parts feature low control logic threshold. Break-before-make switching is guaranteed.

The DG2523 and DG2524 exhibit low parasitic capacitance, low leakage, and highly matched low and flat switch resistance over the full signal range characters that are important for precision analog designs.

The high bandwidth and excellent total harmonic distortion (THD) performance make them ideal for both analog and digital signal switching in space constrain applications requiring high performance and efficient use of board space.

The DG2523 and DG2524 come in Pb-free QFN-16 package of 3 mm x 3 mm.

BENEFITS

- · Low and flat resistance
- · Excellent total harmonic distortion
- · Low parasitic capacitance
- Low voltage control interface

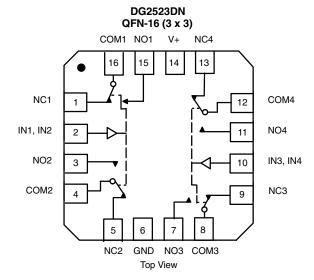
FEATURES

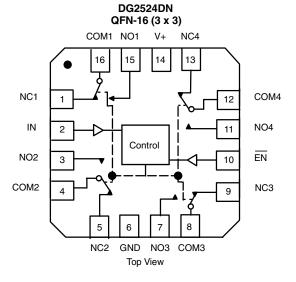
- 1.8 V to 5.5 V single supply operation
- Low resistance: 0.4 Ω / typ. at 2.7 V
- Highly flat and matched Ron
- Low parasitic capacitance,
 C_{on} = 26 pF, C_{off} = 14.5 pF
- Typical switch off leakage of 40 pA
- High bandwidth: 310 MHz
- Guaranteed logic high 1.2 V, logic low 0.3 V
- Break before make switching
- Signal swing over V+ capable
- Power down protection
- Latch up current: 300 mA (JESD78)
- ESD/HBM: > 6 kV
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- · Automatic test equipment
- Data acquisition systems
- Meters and instruments
- Medical and healthcare systems
- · Communication systems
- · Audio and video signal routing
- Battery powered systems
- Computer peripherals
- Data storage
- Relay replacement

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION





Document Number: 67894



Vishay Siliconix

TRUTH TABLE DG2523								
INx	NC1, 2, 3, and 4	NO1, 2, 3, and 4						
0	On	Off						
1	Off	On						

TRUTH TABLE DG2524									
EN	LOGIC IN	NC1, 2, 3, and 4	NO1, 2, 3, and 4						
1	х	Off	Off						
0	0	On	Off						
0	1	Off	On						

ORDERING INFORMATION									
TEMPERATURE RANGE	PACKAGE	PART NUMBER	MIN. ORDER / PACK. QUANTITY						
-40 °C to +85 °C lead (Pb)-free	QFN-16 (3 mm x 3 mm)	DG2523DN-T1-GE4	Tape and reel, 2500 units						
	QFN-10 (3 IIIII X 3 IIIII)	DG2524DN-T1-GE4	rape and reel, 2500 units						

ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C, unless otherwise noted)									
PARAMETER		SYMBOL	LIMIT	UNIT					
Reference to GND	V+		-0.3 to +6	V					
Reference to GND	IN, COM, NC, NO a		-0.3 to (V+ + 0.3)						
Current (any terminal except NO, NC, or	COM)		30						
Continuous current (NO, NC, or COM)			± 300	mA					
Peak current (pulsed at 1 ms, 10 % duty	cycle)		± 500						
Storage temperature (D suffix)		-65 to +150	°C						
Package solder reflow conditions ^d QFN-16			250						
Power dissipation (packages) ^b	QFN-16 °		1385	mW					

Notes

- a. Signals on NC, NO, or COM, or IN exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC board.
- c. Derate 17.3 mW/°C above 70 °C.
- d. Manual soldering with iron is not recommended for leadless components. The miniQFN-16 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper lip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



www.vishay.com

Vishay Siliconix

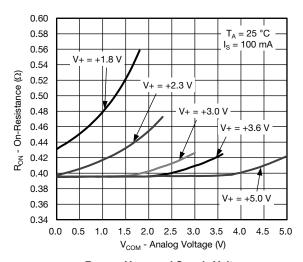
Analog Switch	PARAMETER	/+ = 3 V)	TEST CONDITIONS unless otherwise specified	TEMP.a	LIMITS -40 °C to +85 °C			UNIT
Analog signal range d VNO, VNC, VCOM Provided Full 0 - V+ VNC NNC Provided Pro	PANAIVIETEN	STWIBOL		I EIVIF.				01411
Non-resistance Rom Pon	Analog Switch			l				
On-resistance Ho For For For For For Content For For Content For For Content For For Content For Conten	Analog signal range ^d			Full	0	-	V+	V
Row flatness Row	On-resistance	R _{ON}	$V+ = 2.7 \text{ V}, V_{COM} = 0 \text{ to } 2.7 \text{ V}, I_{NO}, I_{NC} = 100 \text{ mA}$					
Rom match d ARom Rom								Ω
Switch off leakage current INO(off) I				Full	-		0.08	
Switch off leakage current Nocient Nacient N	R _{ON} match ^d	ΔR _{ON}	I _{NO} , I _{NC} = 100 mA	Room	-	0.05	-	
Switch off leakage current I _{COM(off)} VCOM = 4 V / 0.5 V Room -1 0.17 1 1 1 1 1 1 1 1 1						0.04		
Com(off)	Switch off leakage current	-140(011)	$V_{+} = 5.5 \text{ V}, V_{NO}, V_{NC} = 0.5 \text{ V} / 4 \text{ V},$ $V_{COM} = 4 \text{ V} / 0.5 \text{ V}$			0.17		
Compon V+ = 5.5 V, V _{NO} , V _{NC} = V _{COM} = 0.5 V / 4 V		I _{COM(off)}	VCOM = 4 V / 0.0 V			-		nA
Compon V + = 3.5 V, Vno, Vnc = Vcom = U.3 V / 4 Full -5 - 5 5	Channel-on leakage			Room	-1	0.17	1	
$ \begin{array}{ c c c c c } \hline Input high voltage & V_{INH} & & & & & & & & & & & & & & & & & & &$	· ·	I _{COM(on)}	$V+ = 5.5 \text{ V}, V_{NO}, V_{NC} = V_{COM} = 0.5 \text{ V} / 4 \text{ V}$		-5	-		
Input low voltage V_{INL}	Digital Control						l l	
Input capacitance C _{IN} C _{IN} Full - 5 - 0.3 C _{IN} Input capacitance C _{IN} Input current Input curr	Input high voltage	V _{INH}			1.2	-	-	.,
Input current Input curre	Input low voltage			Full	-	-	0.3	V
Input current Input curre	Input capacitance	C _{IN}		Full	-	5	-	pF
Turn-on time to N Turn-off time to FF to FF Turn-off time to Fill Turn-off time to Full Turn-off time to Full Turn-off time to Full Turn-off time to Full Turn-off time Turn-off time to Full Turn-off time Turn-off time to Full Turn-off time Turn-off time to Charges In Full Turn-off time Turn-off time Turn-off time Turn-off time to Charges In Full Turn-off time Turn-off	Input current		$V_{IN} = 0$ or $V+$	Full	-1	-	1	μA
Turn-on time ton ton toff	Dynamic Characteristics							
Turn-off time Turn-off turn-off Turn-o	Turn on time	+		Room	-	38	60	
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	rum-on time	ION	VV 45V B 50 0 05 15	Full	-	-	70	μs
Sin	Turn off time	t _{OFF}	$V_{NO} \text{ or } V_{NC} = 1.5 \text{ V}, \text{ RL} = 50 \Omega, \text{ GL} = 35 \text{ pr}$	Room	-	0.43	1	
	rum-on time			Full	-	-	3	
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	Break-before-make time	t _d		Full	1	-	-	
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	Charge injection ^d	Q _{INJ}	C_L = 1 nF, V_{GEN} = 1.5 V, R_{GEN} = 0 Ω	Room	-	-19	-	рС
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	-3 dB bandwidth	BW	$R_L = 50 \Omega$, $C_L = 5 pF$	Room	-	310	-	MHz
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	Off inclation d	OIRR	$R_L = 50 \Omega$, $C_L = 5 pF$, $f = 100 kHz$		-	-82	-	
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	OII-ISOIALIOII "	Oinn	$R_L = 50 \Omega$, $C_L = 5 pF$, $f = 1 MHz$	Room	-	-55	-	dB
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	Croostally d f	~	$R_L = 50 \Omega$, $C_L = 5 pF$, $f = 100 kHz$		-	-89	-	
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	Grosstaik 4, 1	^TALK	$R_L = 50 \Omega$, $C_L = 5 pF$, $f = 1 MHz$		-	-61	-	
NO, NC off capacitance $\frac{1}{C_{NC(off)}}$ $\frac{14.5}{C_{NC(off)}}$ $\frac{1}{C_{NO(on)}}$ $\frac{14.5}{C_{NO(on)}}$ $\frac{1}{C_{NO(on)}}$ $\frac{14.5}{C_{NO(on)}}$ $\frac{1}{C_{NO(on)}}$ $\frac{1}{C_{NO(on)}}$ Power Supply range $\frac{1}{C_{NO(on)}}$ $\frac{1}{C_{NO(on)}$		THD + N			-	-100	-	
	<u> </u>	C _{NO(off)}		Room	-	14.5	-	pF
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$					-	14.5	-	
C C C C C C C C C C			† = 1 MHz		-	26	-	
Power Supply Power supply range V+ 1.8 - 5.5 N	Channel-on capacitance ^a				-	26	-	
117 3	Power Supply	<u>, , , , , , , , , , , , , , , , , , , </u>						
Power supply current I+ V _{IN} = 0 or V+ Full - 29 60 II	Power supply range	V+			1.8	-	5.5	V
· · · · · · · · · · · · · · · · · · ·	Power supply current	I+	$V_{IN} = 0$ or V+	Full	-	29	60	μA

Notes

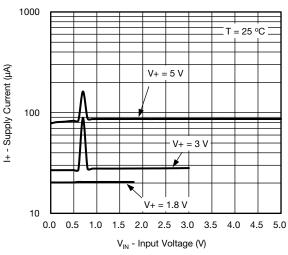
- a. Room = 25 $^{\circ}$ C, full = as determined by the operating suffix.
- b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- c. Typical values are for design aid only, not guaranteed nor subject to production testing.
- d. Guarantee by design, not subjected to production test.
- e. V_{IN} = input voltage to perform proper function.
- f. Crosstalk measured between channels.



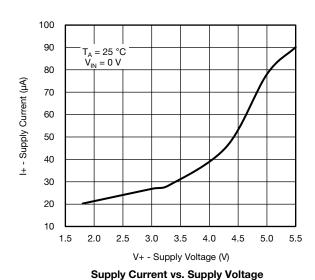
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

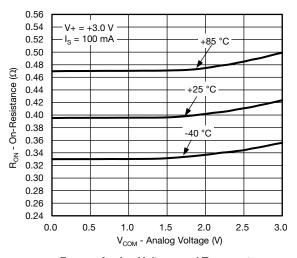


 R_{ON} vs. V_{COM} and Supply Voltage

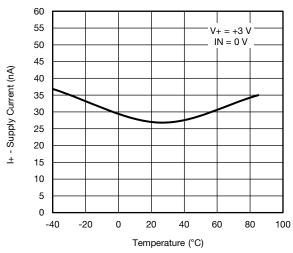


Supply Current vs. Input Voltage

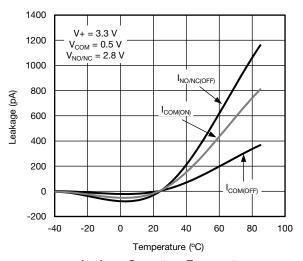




R_{ON} vs. Analog Voltage and Temperature



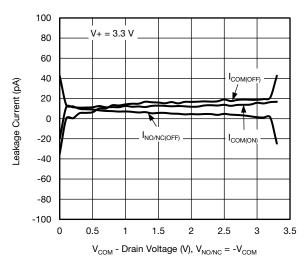
Supply Current vs. Temperature



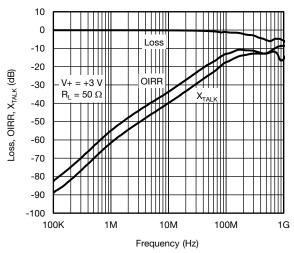
Leakage Current vs. Temperature



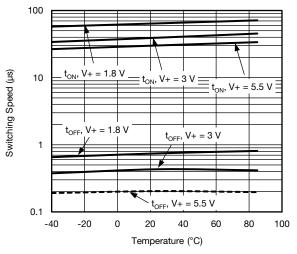
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



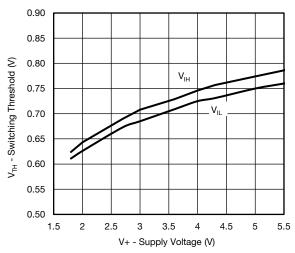
Leakage Current vs. Drain Voltage



Insertion Loss, Off-Isolation Crosstalk vs. Frequency



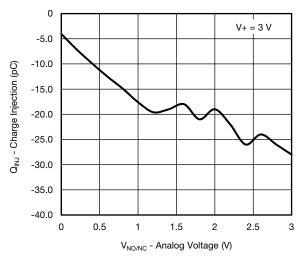
Switching Time vs. Temperature



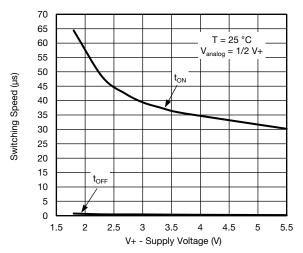
Switching Threshold vs. Supply Voltage



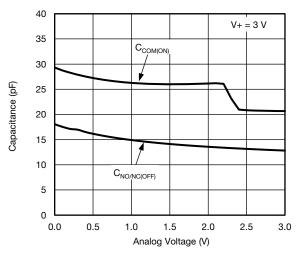
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



Charge Injection vs. Analog Voltage



Switching Time vs. Supply Voltage

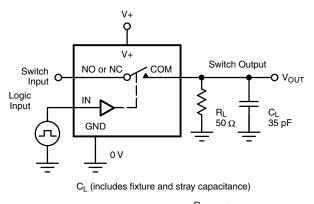


Capacitance vs. Analog Voltage

 t_r < 5 ns



TEST CIRCUITS



Logic 50 % $t_f < 5 \text{ ns}$ Input V_{INL} 0.9 x V_{OUT} Switch Output 0 V t_{ON}

 V_{INH}

$$V_{OUT} = V_{COM} \left(\frac{R_L}{R_L + R_{ON}} \right)$$

Logic "1" = Switch On Logic input waveforms inverted for switches that have the opposite logic sense.

Fig. 1 - Switching Time

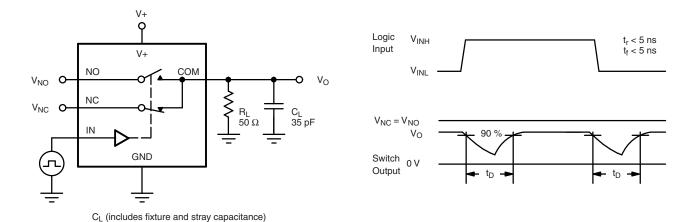


Fig. 2 - Break-Before-Make Interval

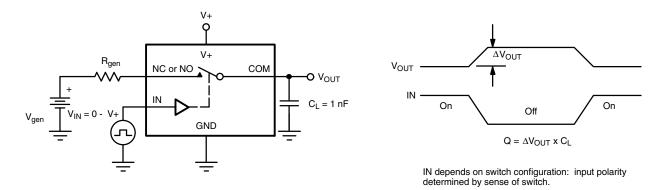


Fig. 3 - Charge Injection

Vishay Siliconix

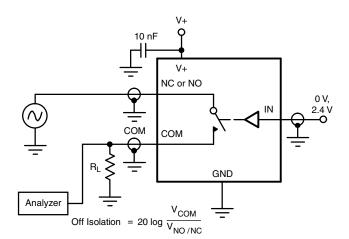


Fig. 4 - Off-Isolation

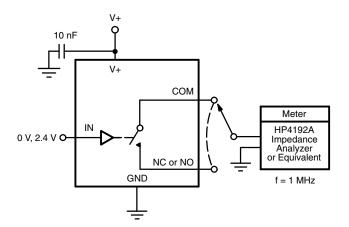
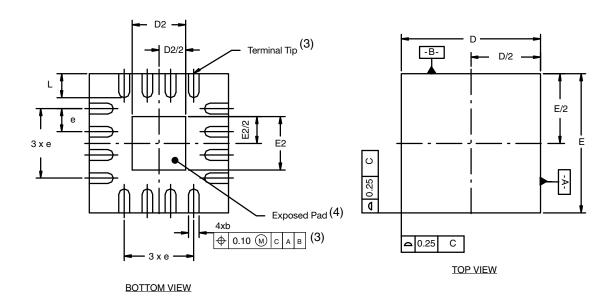


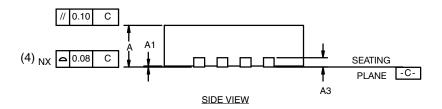
Fig. 5 - Channel Off / On Capacitance

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg267894.



QFN-16 Lead (3 x 3)





Notes

- (1) All dimensions are in millimeters.
- (2) N is the total number of terminals.
- (3) Dimension b applies to metallized terminal and is measured between 0.25 and 0.30 mm from terminal tip.
- (4) Coplanarity applies to the exposed heat sink slug as well as the terminal.
- (5) The pin #1 identifier may be either a mold or marked feature, it must be located within the zone indicated.

			VARIA	TION 1		VARIATION 2						
DIM.	MILLIMETERS		INCHES		MILLIMETERS			INCHES				
	MIN.	NOM	MAX.	MIN.	NOM	MAX.	MIN.	NOM	MAX.	MIN.	NOM	MAX.
Α	0.80	0.90	1.00	0.031	0.035	0.039	0.80	0.90	1.00	0.031	0.035	0.039
b	0.18	0.23	0.30	0.007	0.009	0.012	0.18	0.25	0.30	0.007	0.010	0.012
D	2.90	3.00	3.10	0.114	0.118	0.122	2.90	3.00	3.10	0.114	0.118	0.122
D2	1.00	1.15	1.25	0.039	0.045	0.049	1.50	1.70	1.80	0.059	0.067	0.071
E	2.90	3.00	3.10	0.114	0.118	0.122	2.90	3.00	3.10	0.114	0.118	0.122
E2	1.00	1.15	1.25	0.039	0.045	0.049	1.50	1.70	1.80	0.059	0.067	0.071
е		0.50 BSC	SC 0.020 BSC		0.50 BSC			0.020 BSC				
L	0.30	0.40	0.50	0.012	0.016	0.020	0.30	0.40	0.50	0.012	0.016	0.020

ECN: T16-0233-Rev. D, 09-May-16

DWG: 5899



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

单击下面可查看定价,库存,交付和生命周期等信息

>>Vishay(威世)